



Precision, 16-Channel/Dual 8-Channel, High-Performance, CMOS Analog Multiplexers

General Description

The MAX306/MAX307 precision, monolithic, CMOS analog multiplexers (muxes) offer low on-resistance (less than 100Ω), which is matched to within 5Ω between channels and remains flat over the specified analog signal range (7Ω , max). They also offer low leakage over temperature ($I_{NO(OFF)}$ less than $2.5nA$ at $+85^\circ C$) and fast switching speeds (t_{TRANS} less than $250ns$). The MAX306 is a single-ended 1-of-16 device, and the MAX307 is a differential 2-of-8 device.

The MAX306/MAX307 are fabricated with Maxim's improved $44V$ silicon-gate process. Design improvements yield extremely low charge injection (less than $10pC$) and guarantee electrostatic discharge (ESD) protection greater than $2000V$.

These muxes operate with a single $+4.5V$ to $+30V$ supply, or bipolar $\pm 4.5V$ to $\pm 20V$ supplies, while retaining TTL/CMOS-logic input compatibility and fast switching. CMOS inputs provide reduced input loading. These improved parts are plug-in upgrades for the industry-standard DG406, DG407, DG506A, and DG507A.

Applications

Sample-and-Hold Circuits	Military Radios
Test Equipment	Communications Systems
Heads-Up Displays	Battery-Operated Systems
Guidance and Control Systems	PBX, PABX
	Audio Signal Routing

Features

- ♦ Guaranteed On-Resistance Match Between Channels, $<5\Omega$ Max
- ♦ Low On-Resistance, $<100\Omega$ Max
- ♦ Guaranteed Flat On-Resistance over Specified Signal Range, 7Ω Max
- ♦ Guaranteed Charge Injection, $<10pC$
- ♦ $I_{NO(OFF)}$ Leakage $<2.5nA$ at $+85^\circ C$
- ♦ $I_{COM(OFF)}$ Leakage $<20nA$ at $+85^\circ C$
- ♦ ESD Protection $>2000V$
- ♦ Plug-In Upgrade for Industry-Standard DG406/DG407/DG506A/DG507A
- ♦ Single-Supply Operation ($+4.5V$ to $+30V$)
Bipolar-Supply Operation ($\pm 4.5V$ to $\pm 20V$)
- ♦ Low Power Consumption, $<1.25mW$
- ♦ Rail-to-Rail Signal Handling
- ♦ TTL/CMOS-Logic Compatible

Ordering Information

PART	TEMP RANGE	PIN-PACKAGE
MAX306CPI	$0^\circ C$ to $+70^\circ C$	28 Plastic DIP
MAX306CWI	$0^\circ C$ to $+70^\circ C$	28 Wide SO
MAX306C/D	$0^\circ C$ to $+70^\circ C$	Dice*
MAX306EPI	$-40^\circ C$ to $+85^\circ C$	28 Plastic DIP
MAX306EWI	$-40^\circ C$ to $+85^\circ C$	28 Wide SO
MAX306EQI	$-40^\circ C$ to $+85^\circ C$	28 PLCC
MAX306EUI	$-40^\circ C$ to $+85^\circ C$	28 TSSOP
MAX306MJI	$-55^\circ C$ to $+125^\circ C$	28 CERDIP

Ordering Information continued at end of data sheet.

*Contact factory for dice specifications.

Pin Configurations/Functional Diagrams/Truth Tables

TOP VIEW			
V+	1	28	COM
N.C.	2	27	V-
N.C.	3	26	NO8
NO16	4	25	NO7
NO15	5	24	NO6
NO14	6	23	NO5
NO13	7	22	NO4
NO12	8	21	NO3
NO11	9	20	NO2
NO10	10	19	NO1
NO9	11	18	EN
GND	12	17	A0
N.C.	13	16	A1
A3	14	15	A2
MAX306		DIP/SO/TSSOP	

A3	A2	A1	A0	EN	ON Switch
X	X	X	X	0	None
0	0	0	0	1	1
0	0	0	1	1	2
0	0	1	0	1	3
0	0	1	1	1	4
0	1	0	0	1	5
0	1	0	1	1	6
0	1	1	0	1	7
0	1	1	1	1	8
1	0	0	0	1	9
1	0	0	1	1	10
1	0	1	0	1	11
1	0	1	1	1	12
1	1	0	0	1	13
1	1	0	1	1	14
1	1	1	0	1	15
1	1	1	1	1	16

MAX306
LOGIC "0" $V_{AL} \leq 0.8V$, LOGIC "1" $= V_{AH} \geq 2.4V$

Pin Configurations/Functional Diagrams/Truth Tables continued at end of data sheet.

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ABSOLUTE MAXIMUM RATINGS

(Voltage Referenced to V-)

V+	-0.3V, +44V
GND	-0.3V, +25V
Digital Inputs, NO, COM (Note 1)	(V- - 2V) to (V+ + 2V) or 30mA (whichever occurs first)
Continuous Current (any terminal)	30mA
Peak Current, NO or COM (pulsed at 1ms, 10% duty cycle max)	100mA
Continuous Power Dissipation (T _A = +70°C)	
28-Pin Plastic DIP	
	(derate 9.09mW/°C above +70°C).....727mW

28-Pin Wide SO (derate 12.50mW/°C above +70°C)	...1000mW
28-Pin PLCC (derate 10.53mW/°C above +70°C)	842mW
28-Pin CERDIP (derate 16.67mW/°C above +70°C)	...1333mW
28-Pin TSSOP (derate 12.8mW/°C above +70°C)	1025mW
Operating Temperature Ranges	
MAX30_C_	0°C to +70°C
MAX30_E_	-40°C to +85°C
MAX30_MJL	-55°C to +125°C
Storage Temperature Range	-65°C to +150°C
Lead Temperature (soldering, 10s)	+300°C

Note 1: Signals on NO, COM, A0, A1, A2, A3, or EN exceeding V+ or V- are clamped by internal diodes. Limit forward current to maximum current ratings.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS—Dual Supplies

(V+ = +15V, V- = -15V, GND = 0V, V_{AH} = +2.4V, V_{AL} = +0.8V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS				MIN	TYP (Note 2)	MAX	UNITS	
SWITCH										
Analog Signal Range	V _{NO} , V _{COM}	(Note 3)				-15		+15	V	
On-Resistance	R _{ON}	I _{NO} = -1.0mA, V _{COM} = ±10V	T _A = +25°C			60		100	Ω	
			T _A = T _{MIN} to T _{MAX}					125		
On-Resistance Matching Between Channels	ΔR _{ON}	I _{NO} = -1.0mA, V _{COM} = ±10V (Note 4)	T _A = +25°C			1.5		5	Ω	
			T _A = T _{MIN} to T _{MAX}					8		
On-Resistance Flatness	R _{FLAT}	I _{NO} = -1.0mA, V _{COM} = ±5V or 0V	T _A = +25°C			1.8		7	Ω	
			T _A = T _{MIN} to T _{MAX}					10		
NO Off-Leakage Current (Note 5)	I _{NO(OFF)}	V _{COM} = ∓10V, V _{NO} = ±10V, V _{EN} = 0V	T _A = +25°C			-0.5	+0.01	+0.5	nA	
			T _A = T _{MIN} to T _{MAX}		C, E	-2.5		+2.5		
					M	-5.0		+5.0		
COM Off-Leakage Current (Note 5)	I _{COM(OFF)}	V _{NO} = ±10V, V _{COM} = ∓10V, V _{EN} = 0V	MAX306	T _A = +25°C		-0.75	+0.02	+0.75	nA	
				T _A = T _{MIN} to T _{MAX}	C, E	-20		+20		
					M	-40		+40		
		V _{NO} = ∓10V, V _{COM} = ±10V, V _{EN} = 0V	MAX307	T _A = +25°C		-0.75	+0.02	+0.75		
				T _A = T _{MIN} to T _{MAX}	C, E	-10		+10		
					M	-20		+20		
COM On-Leakage Current (Note 5)	I _{COM(ON)}	V _{COM} = ±10V, V _{NO} = ±10V, sequence each switch on	MAX306	T _A = +25°C		-0.75	+0.02	+0.75	nA	
				T _A = T _{MIN} to T _{MAX}	C, E	-25		+25		
					M	-50		+50		
				MAX307	T _A = +25°C		-0.75	+0.02		+0.75
					T _A = T _{MIN} to T _{MAX}	C, E	-12.5			+12.5
						M	-25			+25

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MAX306/MAX307

ELECTRICAL CHARACTERISTICS—Dual Supplies (continued)

(V+ = +15V, V- = -15V, GND = 0V, V_{AH} = +2.4V, V_{AL} = +0.8V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP (Note 2)	MAX	UNITS
INPUT							
Input Current with Input Voltage High	I _{AH}	V _A = 2.4V or 15V		-1.0		+1.0	μA
Input Current with Input Voltage Low	I _{AL}	V _{EN} = 0V or 2.4V, V _A = 0V		-1.0		+1.0	μA
SUPPLY							
Power-Supply Range				±4.5		±20	V
Positive Supply Current	I+	V _{EN} = V _A = 0V or 5.0V	T _A = +25°C	16		30	μA
			T _A = T _{MIN} to T _{MAX}			75	
		V _{EN} = 2.4V, V _{A(ALL)} = 0V	T _A = +25°C	0.075		0.5	mA
			T _A = T _{MIN} to T _{MAX}			1	
Negative Supply Current	I-	V _{EN} = 2.4V, V _{A(ALL)} = 0V	T _A = +25°C	-1		+1	μA
			T _A = T _{MIN} to T _{MAX}	-10		+10	
DYNAMIC							
Transition Time	t _{TRANS}	Figure 2	T _A = +25°C	110		300	ns
			T _A = T _{MIN} to T _{MAX}			400	
Break-Before-Make Interval	t _{OPEN}	Figure 4	T _A = +25°C	10		40	ns
Enable Turn-On Time	t _{ON(EN)}	Figure 3	T _A = +25°C	130		200	ns
			T _A = T _{MIN} to T _{MAX}			400	
Enable Turn-Off Time	t _{OFF(EN)}	Figure 3	T _A = +25°C	55		150	ns
			T _A = T _{MIN} to T _{MAX}			300	
Charge Injection (Note 3)	Q	C _L = 1.0nF, V _{NO} = 0V, R _S = 0Ω, Figure 5	T _A = +25°C	2		10	pC
Off-Isolation (Note 6)	V _{ISO}	V _{EN} = 0V, R _L = 1kΩ, f = 100kHz, Figure 6	T _A = +25°C			-69	dB
Crosstalk Between Channels	V _{CT}	V _{EN} = 2.4V, f = 100kHz, V _{GEN} = 1V _{p-p} , R _L = 1kΩ, Figure 7	T _A = +25°C			-92	dB
Logic Input Capacitance	C _{IN}	f = 1MHz	T _A = +25°C	8			pF
NO Off-Capacitance	C _{NO(OFF)}	f = 1MHz, V _{EN} = V _{NO} = 0V, Figure 8	T _A = +25°C	8			pF
COM Off-Capacitance	C _{COM(OFF)}	f = 1MHz, V _{EN} = 0.8V, V _{COM} = 0V, Figure 8	T _A = +25°C		130		pF
					65		
COM On-Capacitance	C _{COM(ON)}	f = 1MHz, V _{EN} = 2.4V, V _{COM} = 0V, Figure 8	T _A = +25°C		140		pF
					70		

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ELECTRICAL CHARACTERISTICS—Single Supply

(V+ = +12V, V- = 0V, GND = 0V, V_{AH} = +2.4V, V_{AL} = +0.8V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP (Note 2)	MAX	UNITS
SWITCH							
Analog Signal Range	V _{NO} , V _{COM}	(Note 3)		0		12	V
On-Resistance	R _{ON}	I _{NO} = -1.0mA V _{COM} = 3V or 10V	T _A = +25°C		120	175	Ω
DYNAMIC							
Transition Time (Note 3)	t _{TRANS}	V _{NO1} = 8V, V _{NO8} = 0V, V _{IN} = 2.4V, Figure 1	T _A = +25°C		130	450	ns
Enable Turn-On Time (Note 3)	t _{ON(EN)}	V _{INH} = 2.4V, V _{INL} = 0V, V _{NO1} = 5V, Figure 3	T _A = +25°C		105	600	ns
Enable Turn-Off Time (Note 3)	t _{OFF(EN)}	V _{INH} = 2.4V, V _{INL} = 0V, V _{NO1} = 5V, Figure 3	T _A = +25°C		80	300	ns
Charge Injection (Note 3)	Q	C _L = 1.0nF, V _{NO} = 0V, R _S = 0Ω	T _A = +25°C		2	10	pC

Note 2: The algebraic convention where the most negative value is a minimum and the most positive value a maximum is used in this data sheet.

Note 3: Guaranteed by design.

Note 4: $\Delta R_{ON} = R_{ON(MAX)} - R_{ON(MIN)}$. On-resistance match between channels and flatness are guaranteed only with specified voltages. Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured at the extremes of the specified analog signal range.

Note 5: Leakage parameters are 100% tested at the maximum-rated hot temperature and guaranteed by correlation at +25°C.

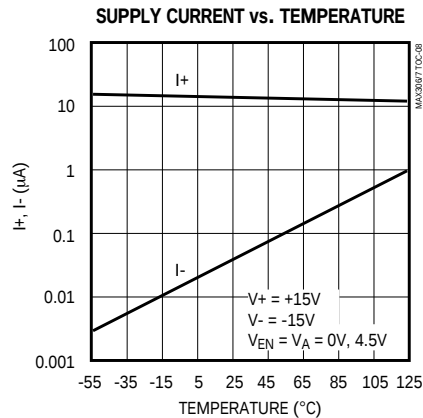
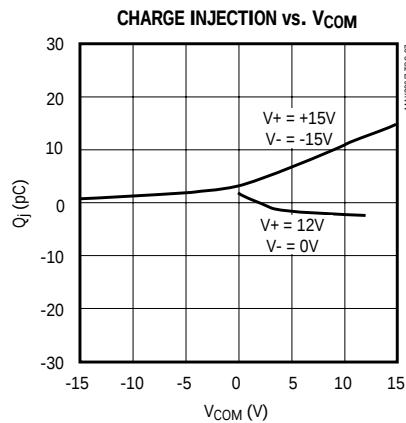
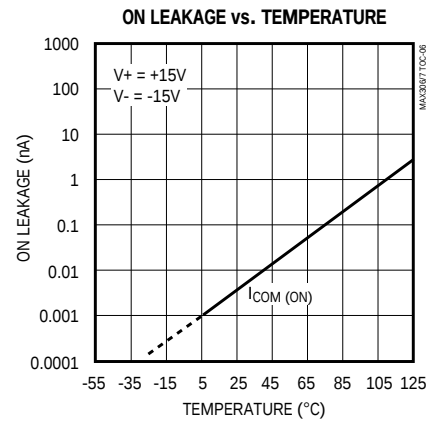
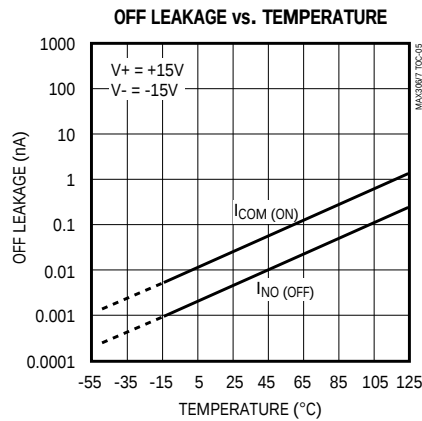
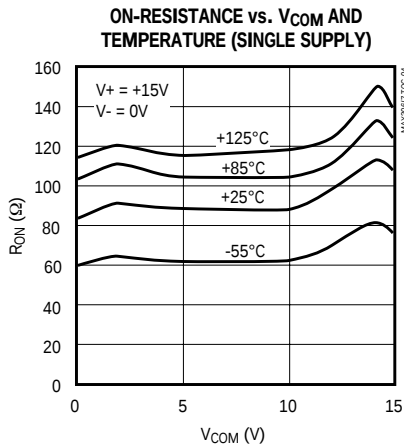
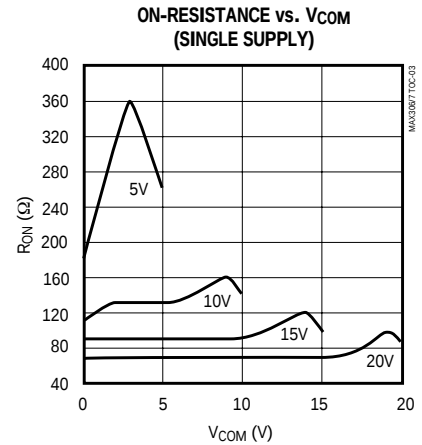
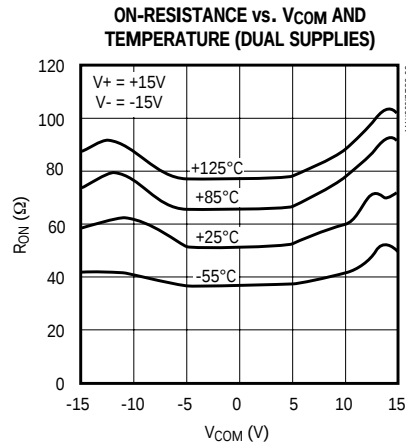
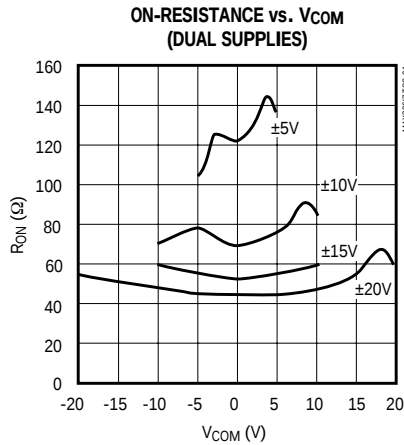
Note 6: Off-isolation = $20 \log V_{COM}/V_{NO}$, where V_{COM} = output and V_{NO} = input to off switch.

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Typical Operating Characteristics

($T_A = +25^\circ\text{C}$, unless otherwise noted.)

MAX306/MAX307



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Pin Descriptions

MAX306 PIN	NAME	FUNCTION
1	V+	Positive Supply Voltage Input
2, 3, 13	N.C.	No Connection. Not internally connected.
4–11	NO16–NO9	Analog Inputs–bidirectional
12	GND	Ground
14–17	A3–A0	Address Inputs
18	EN	Enable Inputs
19–26	NO1–NO8	Analog Inputs–bidirectional
27	V-	Negative Supply Voltage Input
28	COM	Output–bidirectional

MAX307 PIN	NAME	FUNCTION
1	V+	Positive Supply Voltage Input
2	COMB	Output B–bidirectional
3, 13, 14	N.C.	No Connection. Not internally connected.
4–11	NO8B–NO1B	Analog Inputs–bidirectional
12	GND	Ground
15, 16, 17	A2, A1, A0	Address Inputs
18	EN	Enable Input
19–26	NO1A–NO8A	Analog Inputs–bidirectional
27	V-	Negative Supply Voltage Input
28	COMA	Output A–bidirectional

Applications Information

Operation with Supply Voltages

Other than $\pm 15\text{V}$

Using supply voltages other than $\pm 15\text{V}$ will reduce the analog signal range. The MAX306/MAX307 switches operate with $\pm 4.5\text{V}$ to $\pm 20\text{V}$ bipolar supplies or with a $+4.5\text{V}$ to $+30\text{V}$ single supply; connect V- to GND when operating with a single supply. Also, both device types can operate with unbalanced supplies such as $+24\text{V}$ and -5V . The *Typical Operating Characteristics* graphs show typical on-resistance with 20V, 15V, 10V, and 5V supplies. (Switching times increase by a factor of two or more for operation at 5V.)

Overvoltage Protection

Proper power-supply sequencing is recommended for all CMOS devices. Do not exceed the absolute maximum ratings because stresses beyond the listed ratings may cause permanent damage to the devices. Always sequence V+ on first, then V-, followed by either the logic inputs, NO or COM. If power-supply sequencing is not possible, add two small-signal diodes in series with supply pins for overvoltage protection (Figure 1). Adding diodes reduces the analog signal

range to 1V above V+ and 1V below V-, but low switch resistance and low leakage characteristics are unaffected. Device operation is unchanged, and the difference between V+ and V- should not exceed $+44\text{V}$.

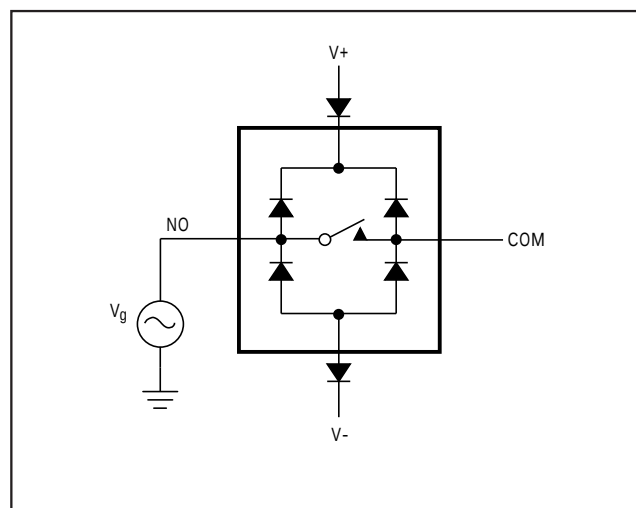


Figure 1. Overvoltage Protection Using External Blocking Diodes

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Test Circuits/Timing Diagrams

MAX306/MAX307

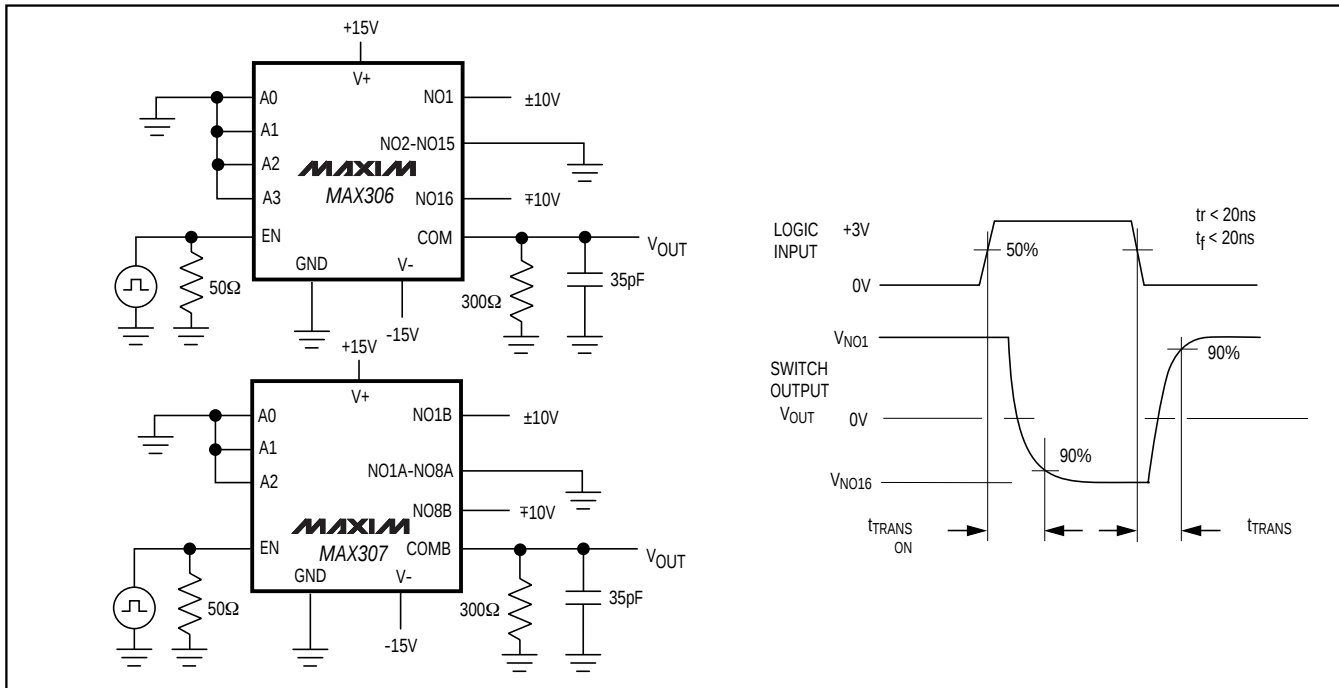


Figure 2. Transition Time

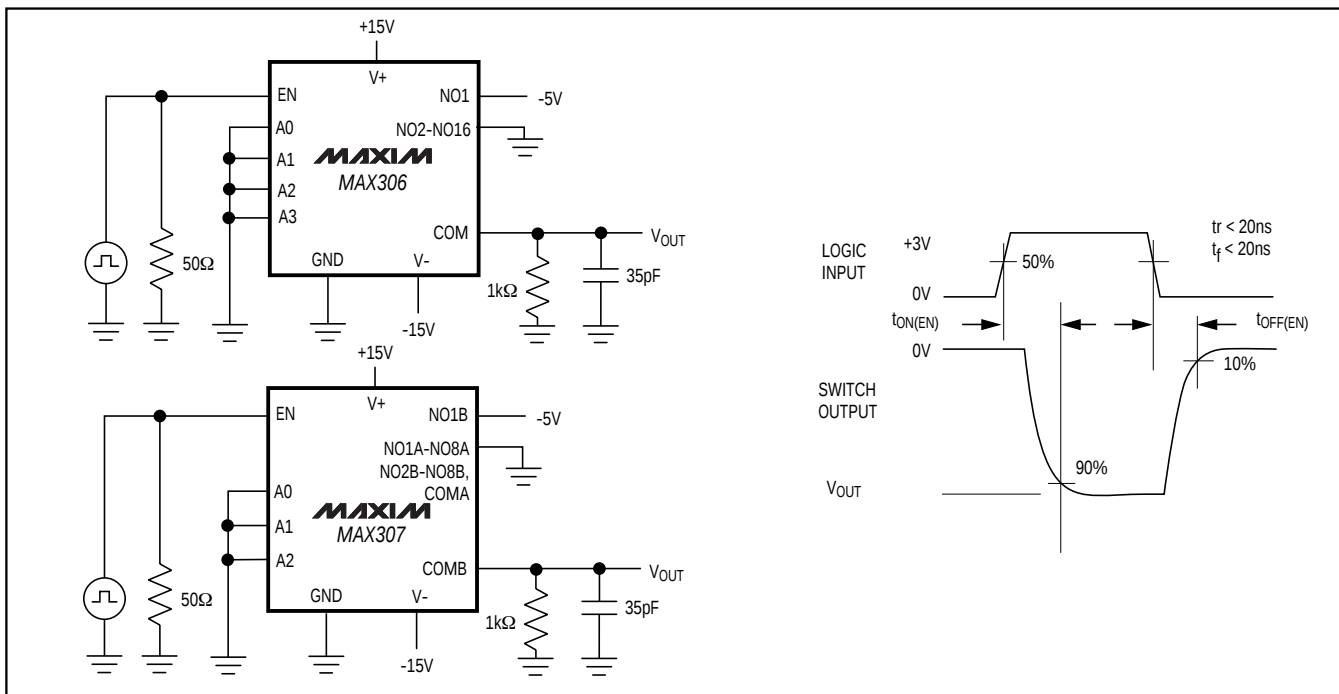


Figure 3. Enable Switching Time

Precision, 16-Channel/Dual 8-Channel, High-Performance, CMOS Analog Multiplexers

Test Circuits/Timing Diagrams (continued)

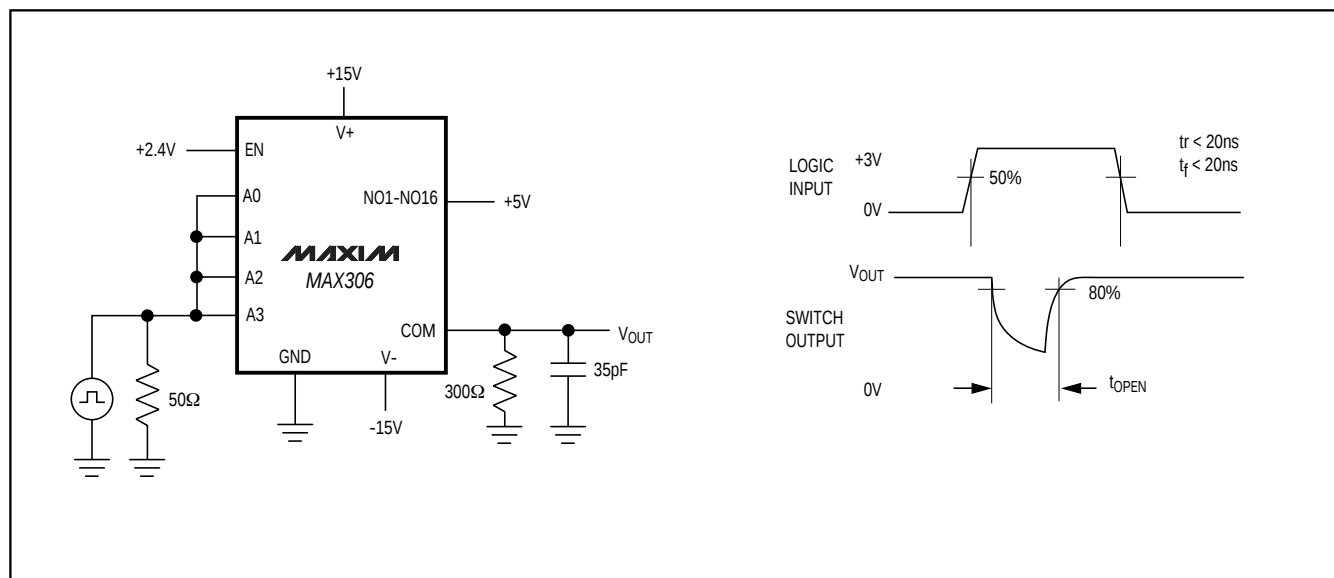


Figure 4. Break-Before-Make Interval

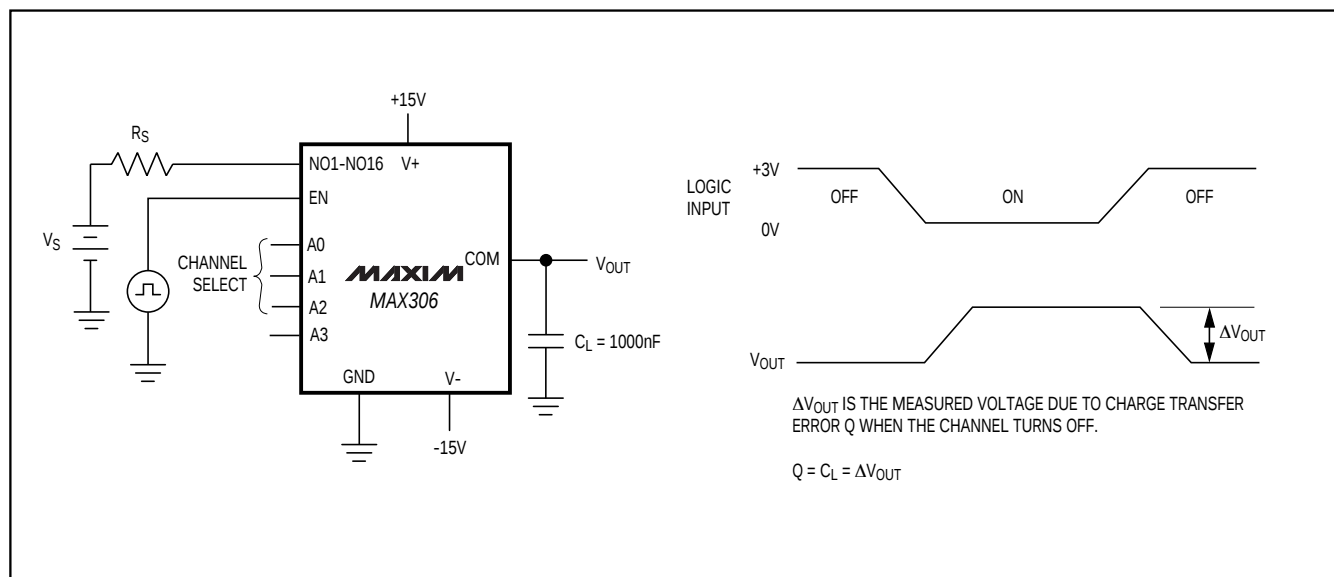


Figure 5. Charge Injection

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Test Circuits/Timing Diagrams (continued)

MAX306/MAX307

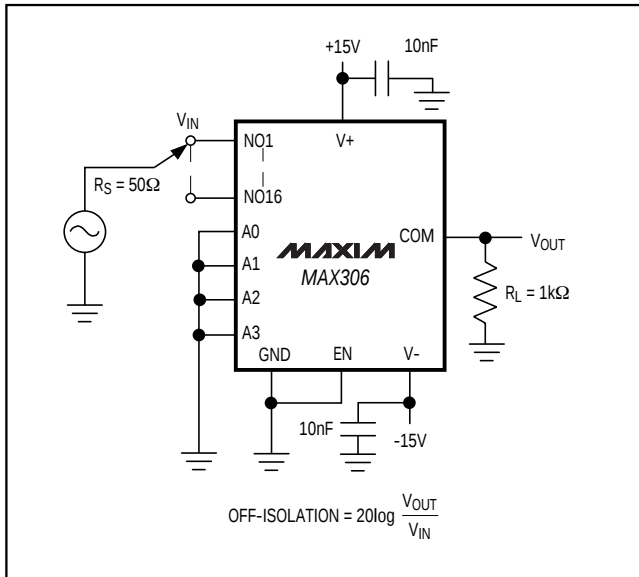


Figure 6. Off-Isolation

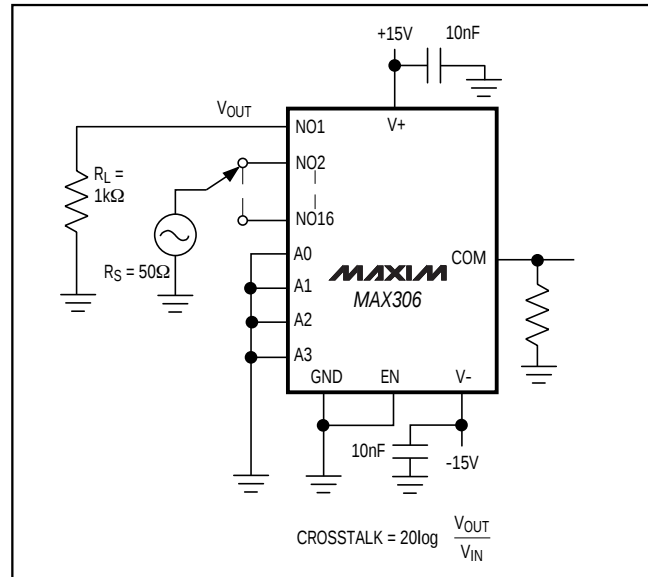


Figure 7. Crosstalk

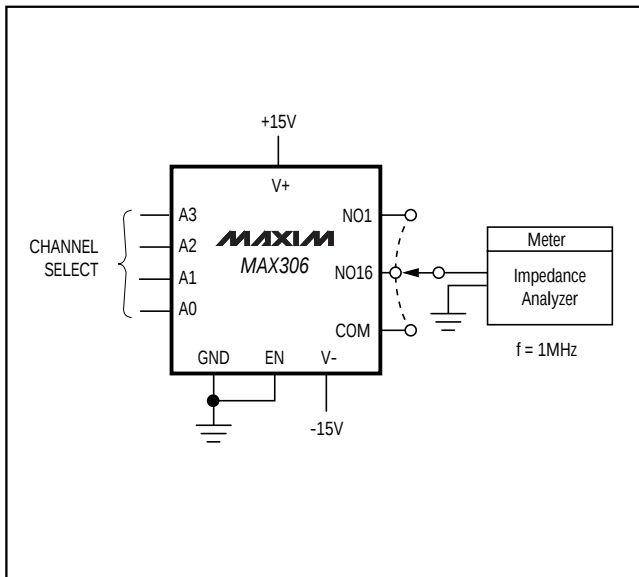
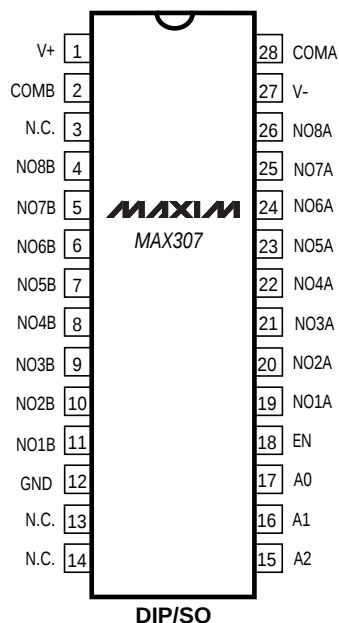


Figure 8. NO/COM Capacitance

Precision, 16-Channel/Dual 8-Channel, High-Performance, CMOS Analog Multiplexers

Pin Configurations/Functional Diagrams/Truth Tables (continued)

TOP VIEW



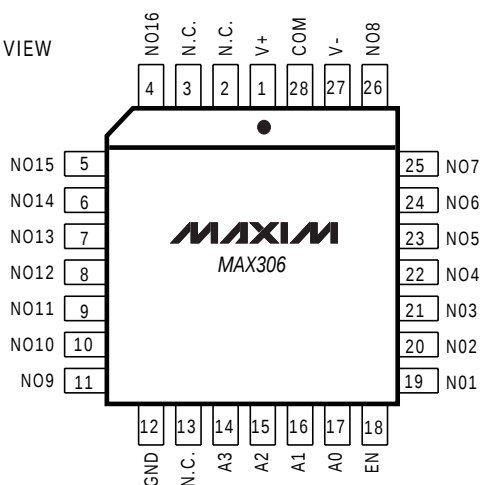
DIP/SO

A2	A1	A0	EN	ON Switch
X	X	X	0	None
0	0	0	1	1
0	0	1	1	2
0	1	0	1	3
0	1	1	1	4
1	0	0	1	5
1	0	1	1	6
1	1	0	1	7
1	1	1	1	8

MAX307

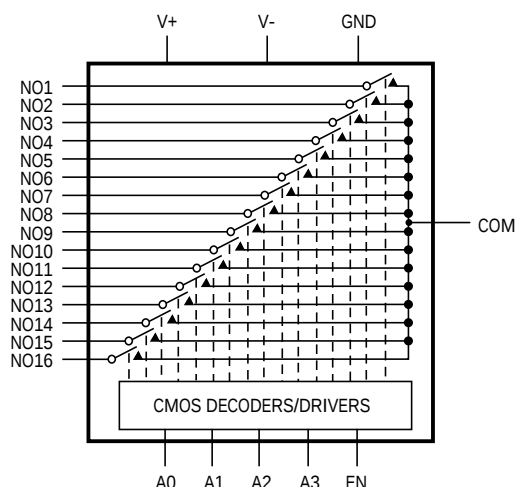
LOGIC "0" $V_{AL} \leq 0.8V$, LOGIC "1" $= V_{AH} \geq 2.4V$

TOP VIEW



PLCC

N.C. = NO INTERNAL CONNECTION

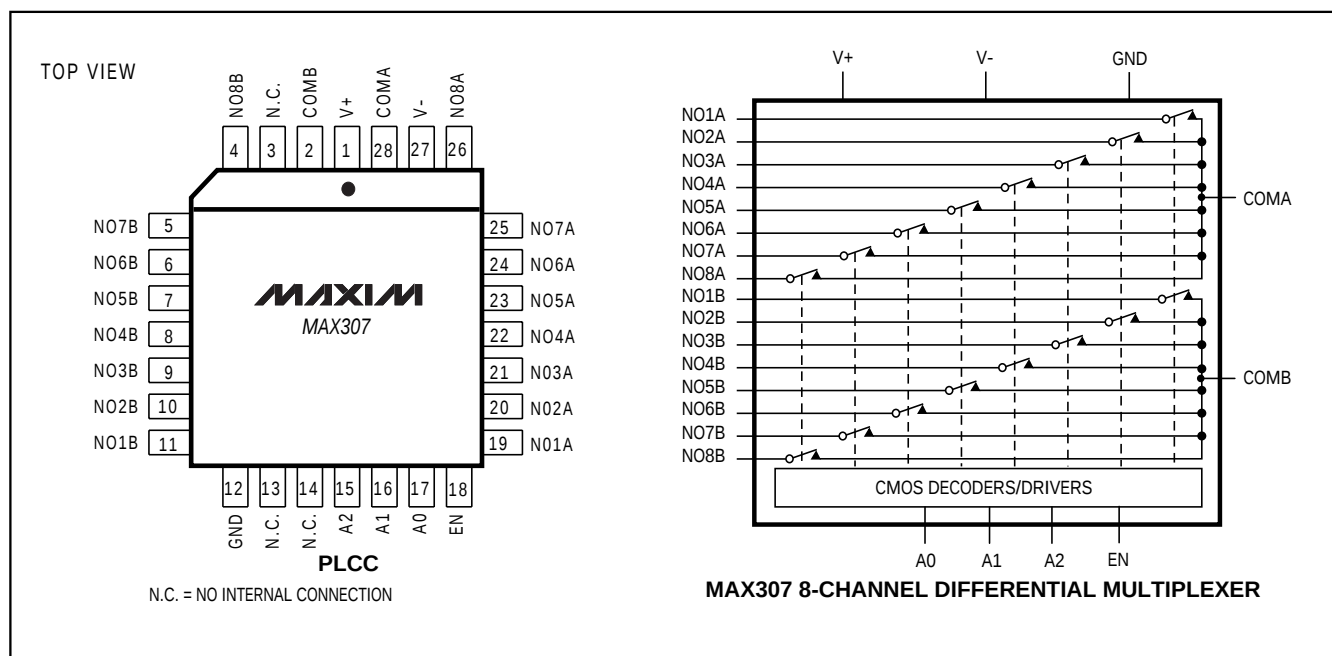


MAX306 16-CHANNEL SINGLE-ENDED MULTIPLEXER

Precision, 16-Channel/Dual 8-Channel, High-Performance, CMOS Analog Multiplexers

Pin Configurations/Functional Diagrams/Truth Tables (continued)

MAX306/MAX307



Ordering Information (continued)

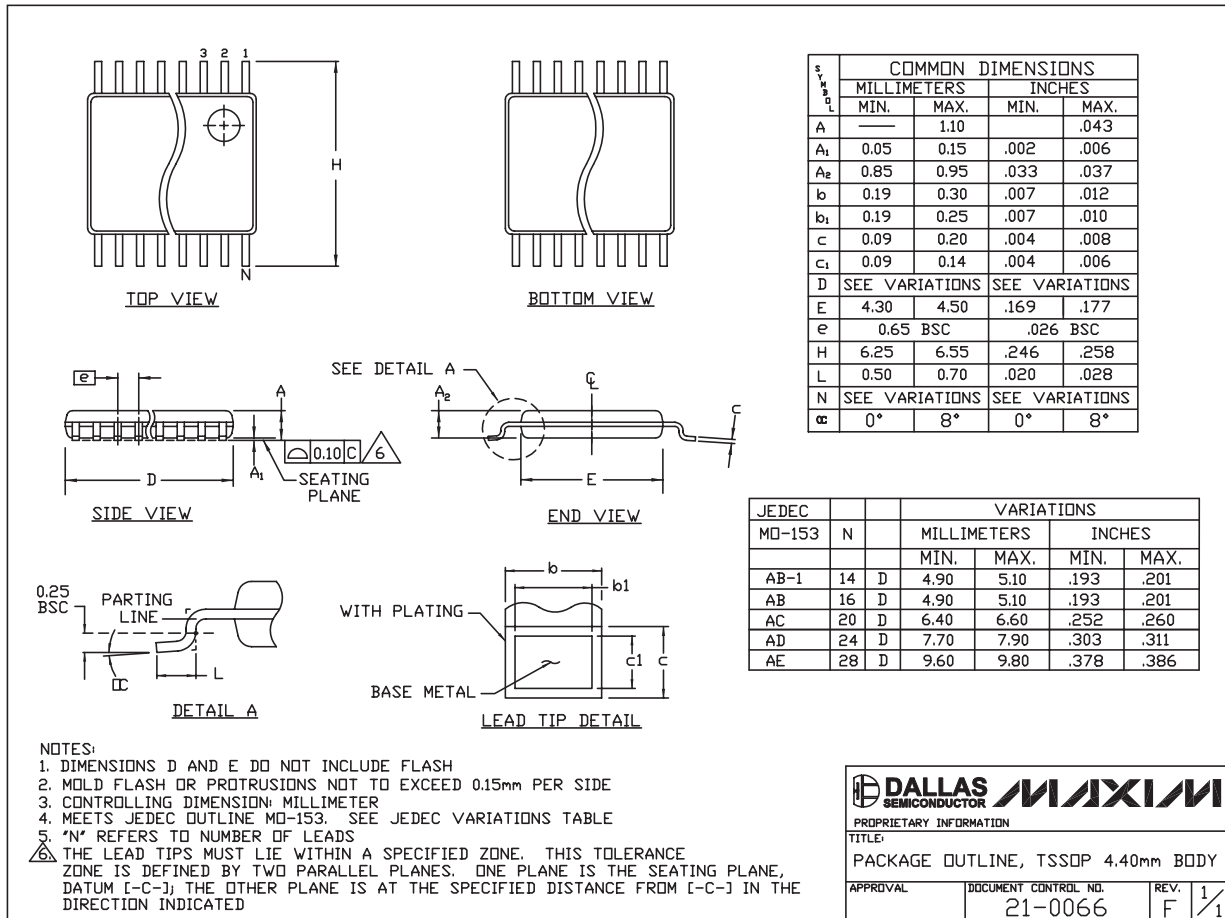
PART	TEMP RANGE	PIN-PACKAGE
MAX307CPI	0°C to +70°C	28 Plastic DIP
MAX307CWI	0°C to +70°C	28 Wide SO
MAX307C/D	0°C to +70°C	Dice*
MAX307EPI	-40°C to +85°C	28 Plastic DIP
MAX307EWI	-40°C to +85°C	28 Wide SO
MAX307EQI	-40°C to +85°C	28 PLCC
MAX307EUI	-40°C to +85°C	28 TSSOP
MAX307MJI	-55°C to +125°C	28 CERDIP

* Contact factory for dice specifications.

Precision, 16-Channel/Dual 8-Channel, High-Performance, CMOS Analog Multiplexers

Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to www.maxim-ic.com/packages.)

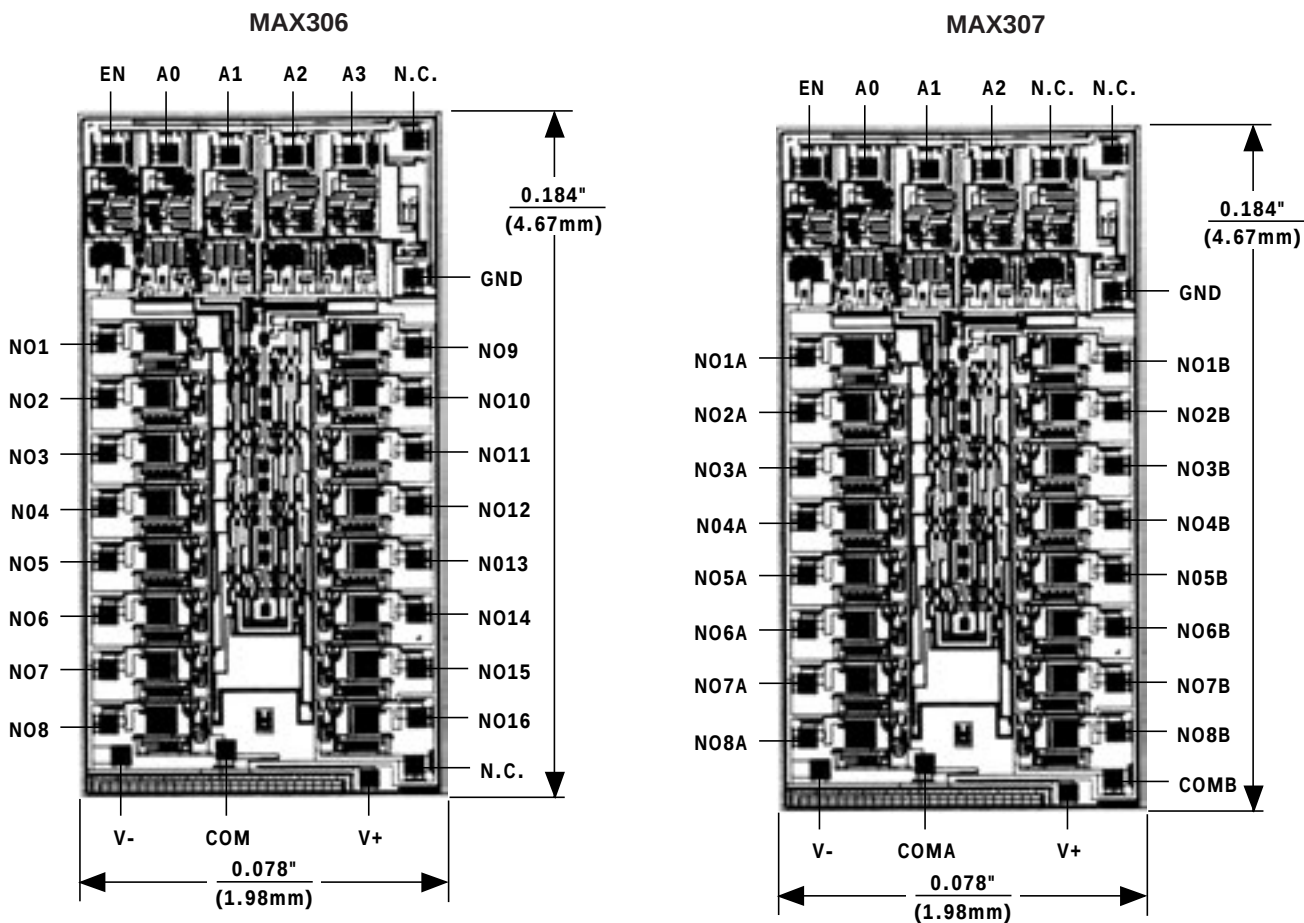


TSSOP4.40mm.EPS

Precision, 16-Channel/Dual 8-Channel, High-Performance, CMOS Analog Multiplexers

Chip Topographies

MAX306/MAX307



N.C. = NO INTERNAL CONNECTION

TRANSISTOR COUNT: 269
SUBSTRATE IS INTERNALLY CONNECTED TO V+

TRANSISTOR COUNT: 269
SUBSTRATE IS INTERNALLY CONNECTED TO V+

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